



# DDTB (LO-R1) C

## PNP PRE-BIASED 500 mA SURFACE MOUNT TRANSISTOR

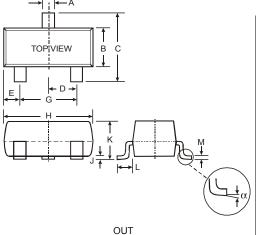
#### **Features**

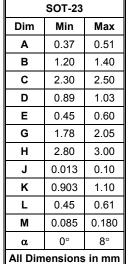
- **Epitaxial Planar Die Construction**
- Complementary NPN Types Available (DDTD)
- **Built-In Biasing Resistors**
- Lead, Halogen and Antimony Free, RoHS Compliant "Green" Device (Notes 1 and 3)

## **Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking Information: See Table Below & Page 3
- Ordering Information: See Page 3
- Weight: 0.008 grams (approximate)

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P/N	R1 (NOM)	R2 (NOM)	Type Code
DDTB122LC	0.22KΩ	10KΩ	P75
DDTB142JC	$0.47$ K $\Omega$	10KΩ	P76
DDTB122TC	$0.22$ K $\Omega$	OPEN	P77
DDTB142TC	0.47ΚΩ	OPEN	P78





3 2 IN GND(+)

Schematic and Pin Diagram

#### **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit		
Supply Voltage, (3) to (2)		Vcc	-50	V		
Input Voltage, (1) to (2)	DDTB122LC DDTB142JC	V <sub>IN</sub>	+5 to -6 +5 to -6	V		
Input Voltage, (2) to (1)	DDTB122TC DDTB142TC	V <sub>EBO (MAX)</sub>	-5	V		
Output Current	All	I <sub>C</sub>	-500	mA		
Power Dissipation	(Note 2)	P <sub>D</sub>	200	mW		
Thermal Resistance, Junction to Ambient Air	(Note 2)	$R_{ hetaJA}$	625	°C/W		
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C		

Notes:

- No purposefully added lead. Halogen and Antimony Free.
- Mounted on FR4 PC Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.

  Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V9 are built with Non-Green Molding Compound and may contain Halogens or Sb₂O₃ Fire Retardants.



## Electrical Characteristics @TA = 25°C unless otherwise specified R1, R2 Types

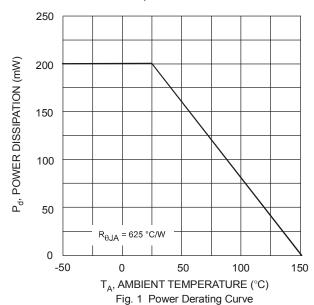
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Input Voltage	DDTB122LC DDTB142JC	V <sub>I(off)</sub>	-0.3 -0.3	_	_	V	V <sub>CC</sub> = -5V, I <sub>O</sub> = -100μA
	DDTB122LC DDTB142JC	V <sub>I(on)</sub>			-2.0 -2.0	/	$V_O = -0.3V$ , $I_O = -20mA$ $V_O = -0.3V$ , $I_O = -20mA$
Output Voltage	$V_{O(on)}$	_	_	-0.3V	V	$I_{O}/I_{I} = -50 \text{mA}/-2.5 \text{mA}$	
Input Current DDTB122LC DDTB142JC		l <sub>l</sub>			-28 -13	mA	V <sub>I</sub> = -5V
Output Current		I <sub>O(off)</sub>			-0.5	μА	V <sub>CC</sub> = -50V, V <sub>I</sub> = 0V
DC Current Gain DDTB122LC DDTB142JC		G <sub>l</sub>	56 56		_	_	V <sub>O</sub> = -5V, I <sub>O</sub> = -50mA
Gain-Bandwidth Product*		f⊤		200	_	MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = -5mA, f = 100MHz

<sup>\*</sup> Transistor - For Reference Only

## Electrical Characteristics @TA = 25°C unless otherwise specified R1- Only Types

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-50		_	V	$I_{C} = -50 \mu A$		
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	-40	_	_	V	I <sub>C</sub> = -1mA		
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-5		_	<b>V</b>	$I_E = -50 \mu A$ $I_E = -50 \mu A$		
Collector Cutoff Current	I <sub>CBO</sub>			-0.5	μА	V <sub>CB</sub> = -50V		
Emitter Cutoff Current DDTB122TC DDTB142TC		I <sub>EBO</sub>			-0.5 -0.5	μА	V <sub>EB</sub> = -4V	
Collector-Emitter Saturation Voltage		V <sub>CE(sat)</sub>			-0.3	V	$I_C = -50$ mA, $I_B = -2.5$ mA	
DC Current Transfer Ratio DDTB122TC DDTB142TC		h <sub>FE</sub>	100 100	250 250	600 600		I <sub>C</sub> = -5mA, V <sub>CE</sub> = -5V	
Gain-Bandwidth Product*		f⊤	_	200	_	MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = 5mA, f = 100MHz	

<sup>\*</sup> Transistor - For Reference Only



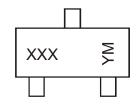


## Ordering Information (Note 4)

Device	Packaging	Shipping
DDTB122LC-7-F	SOT-23	3000/Tape & Reel
DDTB142JC-7-F	SOT-23	3000/Tape & Reel
DDTB122TC-7-F	SOT-23	3000/Tape & Reel
DDTB142TC-7-F	SOT-23	3000/Tape & Reel

Notes: 4. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



XXX = Product Type Marking Code, See Table on Page 1

YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	200	6	2007		2008		2009			2011	2012	
Code	Т		U		V	V W		Х		Υ	Z	
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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